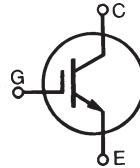


High Voltage IGBT

IXGH 10N170A
IXGT 10N170A

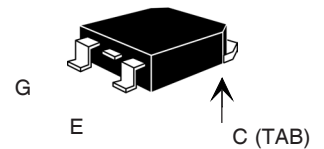
V_{CES} = 1700 V
I_{C25} = 10 A
V_{CE(sat)} = 6.0 V
t_{fi(typ)} = 35 ns

Preliminary Data Sheet

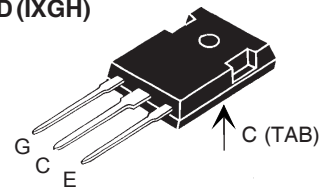


Symbol	Test Conditions	Maximum Ratings	
V _{CES}	T _J = 25°C to 150°C	1700	V
V _{CGR}	T _J = 25°C to 150°C; R _{GE} = 1 MΩ	1700	V
V _{GES}	Continuous	±20	V
V _{GEM}	Transient	±30	V
I _{C25}	T _C = 25°C	10	A
I _{C90}	T _C = 90°C	5	A
I _{CM}	T _C = 25°C, 1 ms	20	A
SSOA (RBSOA)	V _{GE} = 15 V, T _{VJ} = 125°C, R _G = 22Ω Clamped inductive load	I _{CM} = 20 @ 0.8 V _{CES}	A
t _{SC}	T _J = 125°C, V _{CE} = 1200 V; V _{GE} = 15 V, R _G = 22Ω	10	μs
P _C	T _C = 25°C	140	W
T _J		-55 ... +150	°C
T _{JM}		150	°C
T _{stg}		-55 ... +150	°C
M _d	Mounting torque (M3)	(TO-247)	1.13/10Nm/lb.in.
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	°C
Weight		TO-247	6 g
		TO-268	4 g

TO-268 (IXGT)



TO-247 AD (IXGH)



G = Gate, C = Collector,
E = Emitter, TAB = Collector

Features

- International standard packages JEDEC TO-268 and JEDEC TO-247 AD
- High current handling capability
- Very high frequency
- MOS Gate turn-on - drive simplicity
- Rugged NPT structure
- Molding epoxies meet UL 94 V-0 flammability classification

Applications

- Pulsar circuits
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

Advantages

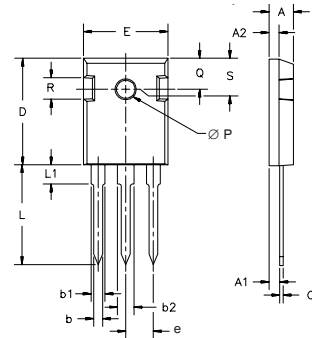
- High power density
- Suitable for surface mounting
- Easy to mount with 1 screw, (isolated mounting screw hole)

Symbol	Test Conditions	Characteristic Values (T _J = 25°C, unless otherwise specified)		
		min.	typ.	max.
BV_{CES}	I _C = 250 μA, V _{GE} = 0 V	1700		V
V_{GE(th)}	I _C = 250 μA, V _{CE} = V _{GE}	3.0		V
I_{CES}	V _{CE} = 0.8 • V _{CES} V _{GE} = 0 V	T _J = 25°C		25 μA
		Note 1 T _J = 125°C		500 μA
I_{GES}	V _{CE} = 0 V, V _{GE} = ±20 V			±100 nA
V_{CE(sat)}	I _C = I _{C90} , V _{GE} = 15 V	T _J = 25°C	4.5	6.0 V
		T _J = 125°C	5.2	V

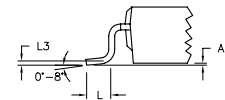
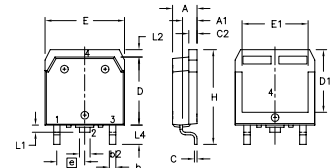
Symbol	Test Conditions	Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified)		
		min.	typ.	max.
g_{fs}	$I_C = I_{C25}; V_{CE} = 20\text{ V}$ Note 2	3	5	S
C_{ies}	$V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$		650	pF
C_{oes}			40	pF
C_{res}			22	pF
Q_G	$I_C = I_{C90}; V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$		29	nC
Q_{GE}			5	nC
Q_{GC}			10	nC
$t_{d(on)}$	Inductive load, $T_J = 25^\circ\text{C}$ $I_C = I_{C25}, V_{GE} = 15\text{ V}$ $R_G = 22\ \Omega, V_{CE} = 0.5 V_{CES}$		46	ns
t_{ri}			57	ns
$t_{d(off)}$			190	360 ns
t_{fi}			35	ns
E_{off}			0.38	0.8 mJ
$t_{d(on)}$	Inductive load, $T_J = 125^\circ\text{C}$ $I_C = I_{C25}, V_{GE} = 15\text{ V}$ $R_G = 22\ \Omega, V_{CE} = 0.5 V_{CES}$		48	ns
t_{ri}			59	ns
E_{on}			1.2	mJ
$t_{d(off)}$			200	ns
t_{fi}			40	ns
E_{off}		0.6	mJ	
R_{thJC}	(TO-247)			0.89 K/W
R_{thCK}			0.25	K/W

Notes: 1. Device must be heatsunk for high temperature leakage current measurements to avoid thermal runaway.

2. Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

TO-247 AD Outline


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
A ₁	2.2	2.54	.087	.102
A ₂	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b ₁	1.65	2.13	.065	.084
b ₂	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L1		4.50		.177
∅P	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	.242	BSC

TO-268 Outline


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.9	5.1	.193	.201
A ₁	2.7	2.9	.106	.114
A ₂	.02	.25	.001	.010
b	1.15	1.45	.045	.057
b ₂	1.9	2.1	.75	.83
C	.4	.65	.016	.026
D	13.80	14.00	.543	.551
E	15.85	16.05	.624	.632
E ₁	13.3	13.6	.524	.535
e	5.45	BSC	.215	BSC
H	18.70	19.10	.736	.752
L	2.40	2.70	.094	.106
L1	1.20	1.40	.047	.055
L2	1.00	1.15	.039	.045
L3		0.25		.010
L4	3.80	4.10	.150	.161

IXYS reserves the right to change limits, test conditions, and dimensions.

Fig. 1. Output Characteristics
@ 25 Deg. C

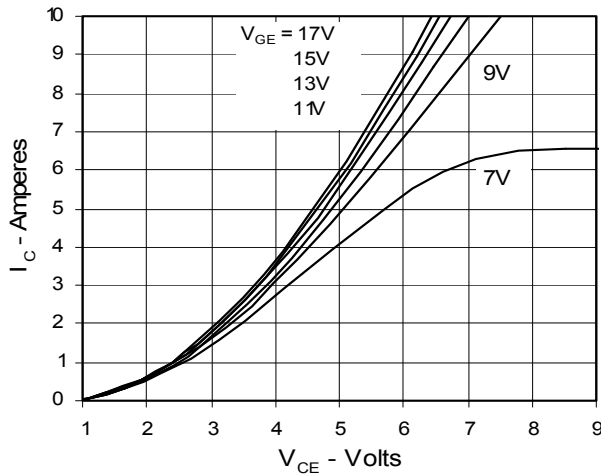


Fig. 2. Extended Output Characteristics
@ 25 deg. C

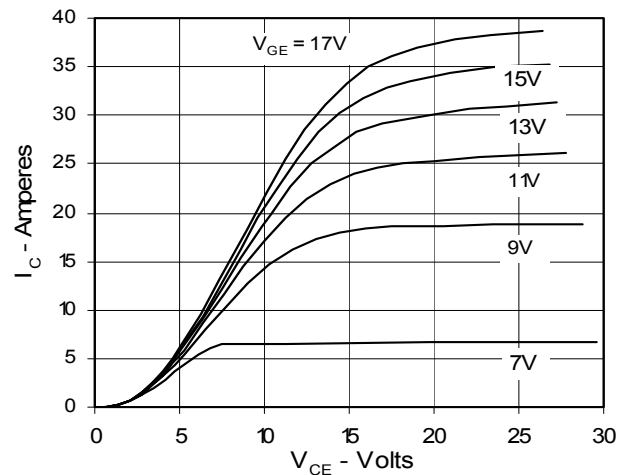


Fig. 3. Output Characteristics
@ 125 Deg. C

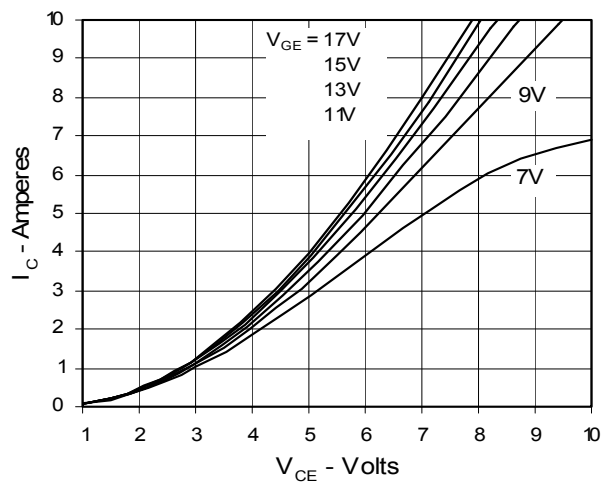


Fig. 4. Temperature Dependence of $V_{CE(sat)}$

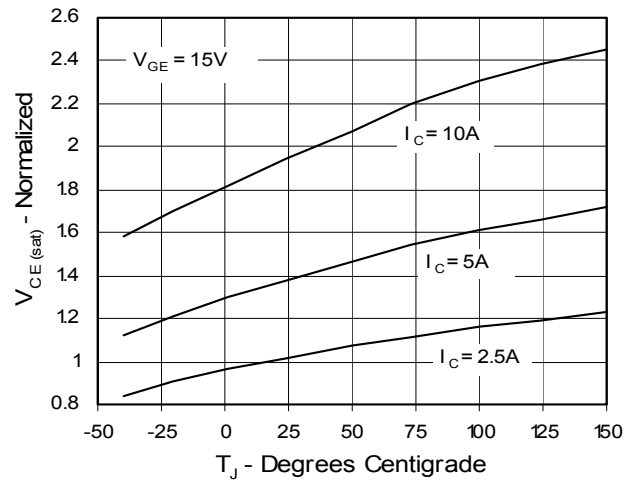


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage

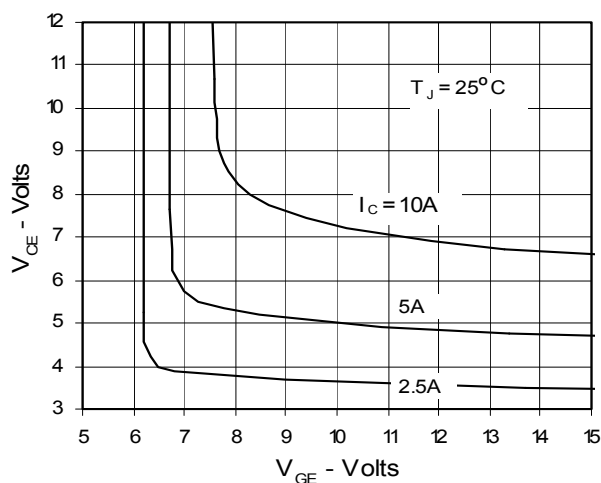


Fig. 6. Input Admittance

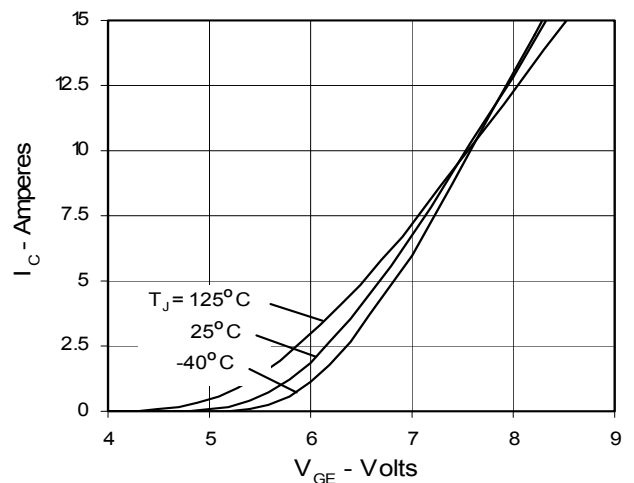


Fig. 7. Transconductance

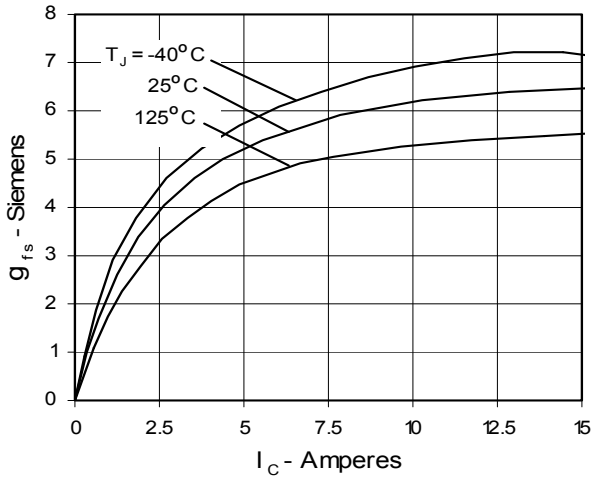


Fig. 8. Dependence of E_{off} on R_G

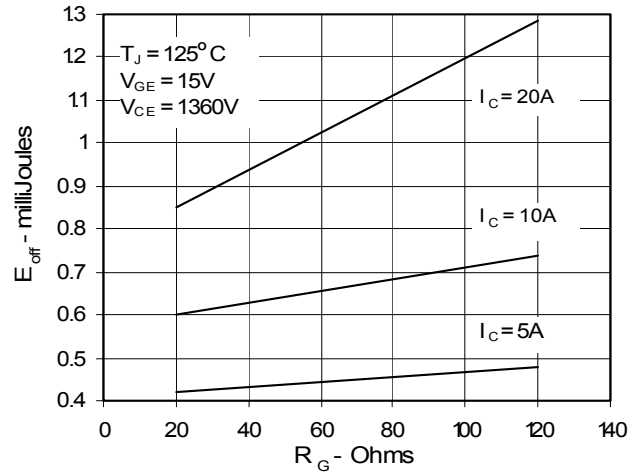


Fig. 9. Dependence of E_{off} on I_C

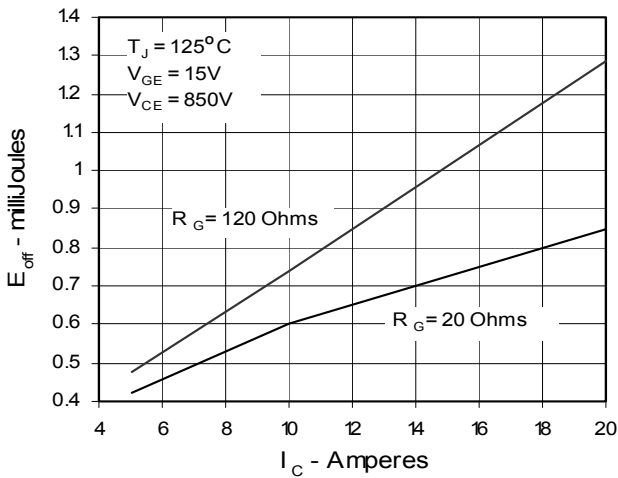


Fig. 10. Dependence of E_{off} on Temperature

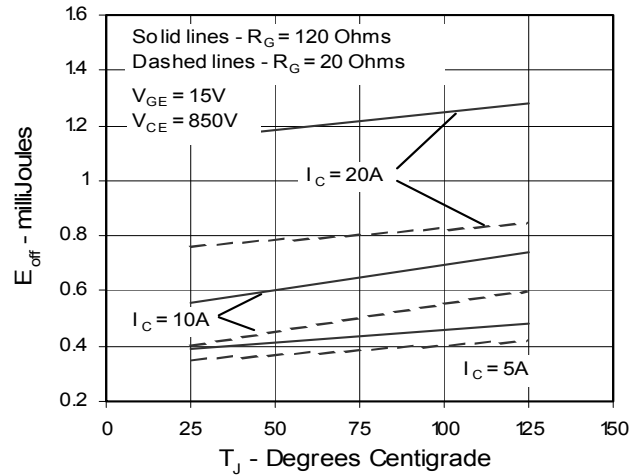


Fig. 11. Gate Charge

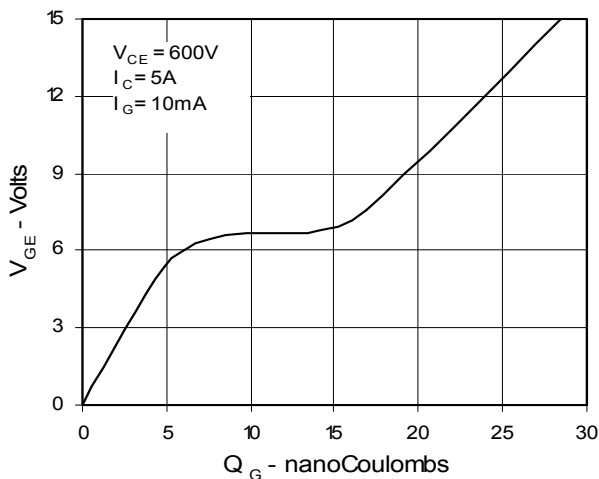
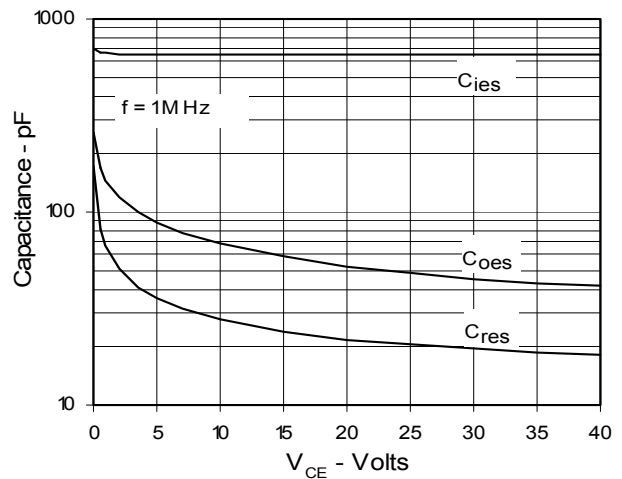
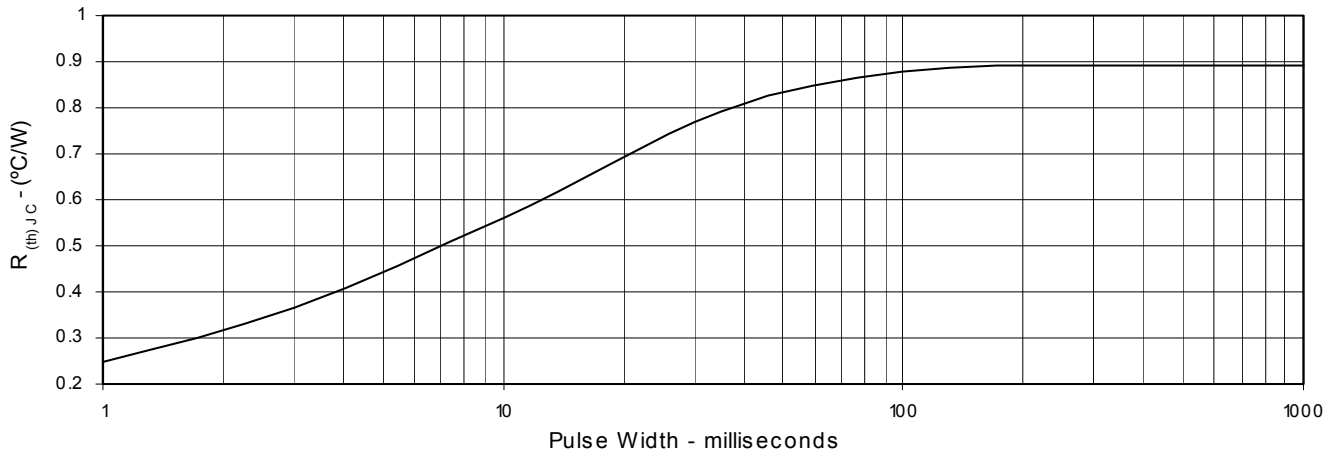


Fig. 12. Capacitance



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Fig. 13. Maximum Transient Thermal Resistance





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